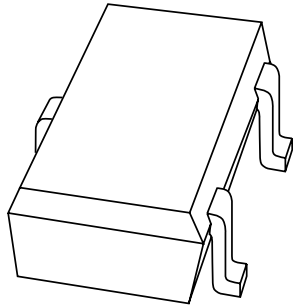


DATA SHEET



PMST2907A PNP switching transistor

Product specification
File under Discrete Semiconductors, SC04

1997 Jul 08

PNP switching transistor

PMST2907A

FEATURES

- Low current (max. 200 mA)
- Low voltage (max. 60 V).

APPLICATIONS

- Medium power switching
- General purpose amplification.

DESCRIPTION

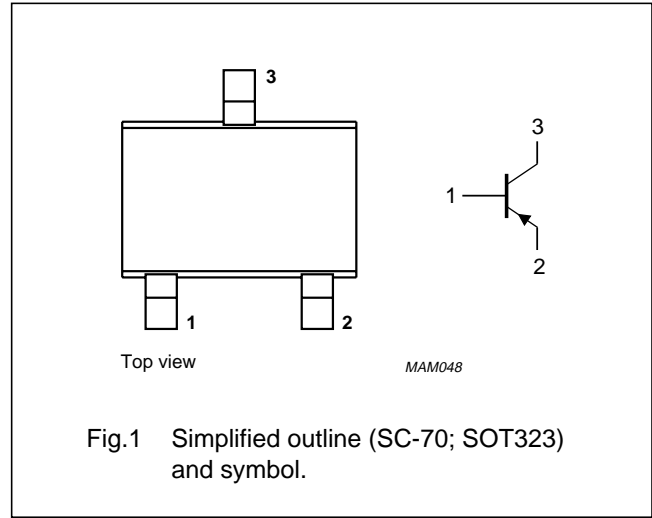
PNP switching transistor in an SC-70; SOT323 plastic package. NPN complement: PMST2222A.

MARKING

TYPE NUMBER	MARKING CODE
PMST2907A	t2F

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	–60	V
V_{CEO}	collector-emitter voltage	open base	–	–60	V
I_C	collector current (DC)		–	–200	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ °C}$	–	200	mW
h_{FE}	DC current gain	$I_C = -500\text{ mA}; V_{CE} = -10\text{ V}$	50	–	
f_T	transition frequency	$I_C = -50\text{ mA}; V_{CE} = -20\text{ V}; f = 100\text{ MHz}$	200	–	MHz
t_{off}	turn-off time	$I_{Con} = -150\text{ mA}; I_{Bon} = -15\text{ mA}; I_{Boff} = 15\text{ mA}$	–	300	ns

PNP switching transistor

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	–60	V
V_{CEO}	collector-emitter voltage	open base	–	–60	V
V_{EBO}	emitter-base voltage	open collector	–	–5	V
I_C	collector current (DC)		–	–200	mA
I_{CM}	peak collector current		–	–200	mA
I_{BM}	peak base current		–	–100	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ °C}$; note 1	–	200	mW
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–	150	°C
T_{amb}	operating ambient temperature		–65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	625	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

$T_{amb} = 25\text{ °C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_{CBO}	collector cut-off current	$I_E = 0$; $V_{CB} = -50\text{ V}$	–	–10	nA
		$I_E = 0$; $V_{CB} = -50\text{ V}$; $T_j = 150\text{ °C}$	–	–10	μA
I_{EBO}	emitter cut-off current	$I_C = 0$; $V_{EB} = -3\text{ V}$	–	–50	nA
h_{FE}	DC current gain	$V_{CE} = -10\text{ V}$			
		$I_C = -0.1\text{ mA}$	75	–	
		$I_C = -1\text{ mA}$	100	–	
		$I_C = -10\text{ mA}$; note 1	100	–	
		$I_C = -150\text{ mA}$; note 1	100	300	
V_{CEsat}	collector-emitter saturation voltage	$I_C = -150\text{ mA}$; $I_B = -15\text{ mA}$; note 1	–	–400	mV
		$I_C = -500\text{ mA}$; $I_B = -50\text{ mA}$; note 1	–	–1.6	V
V_{BEsat}	base-emitter saturation voltage	$I_C = -150\text{ mA}$; $I_B = -15\text{ mA}$; note 1	–	–1.3	V
		$I_C = -500\text{ mA}$; $I_B = -50\text{ mA}$; note 1	–	–2.6	V
C_c	collector capacitance	$I_E = i_e = 0$; $V_{CB} = -10\text{ V}$; $f = 1\text{ MHz}$	–	8	pF
C_e	emitter capacitance	$I_C = i_c = 0$; $V_{EB} = -2\text{ V}$; $f = 1\text{ MHz}$	–	30	pF

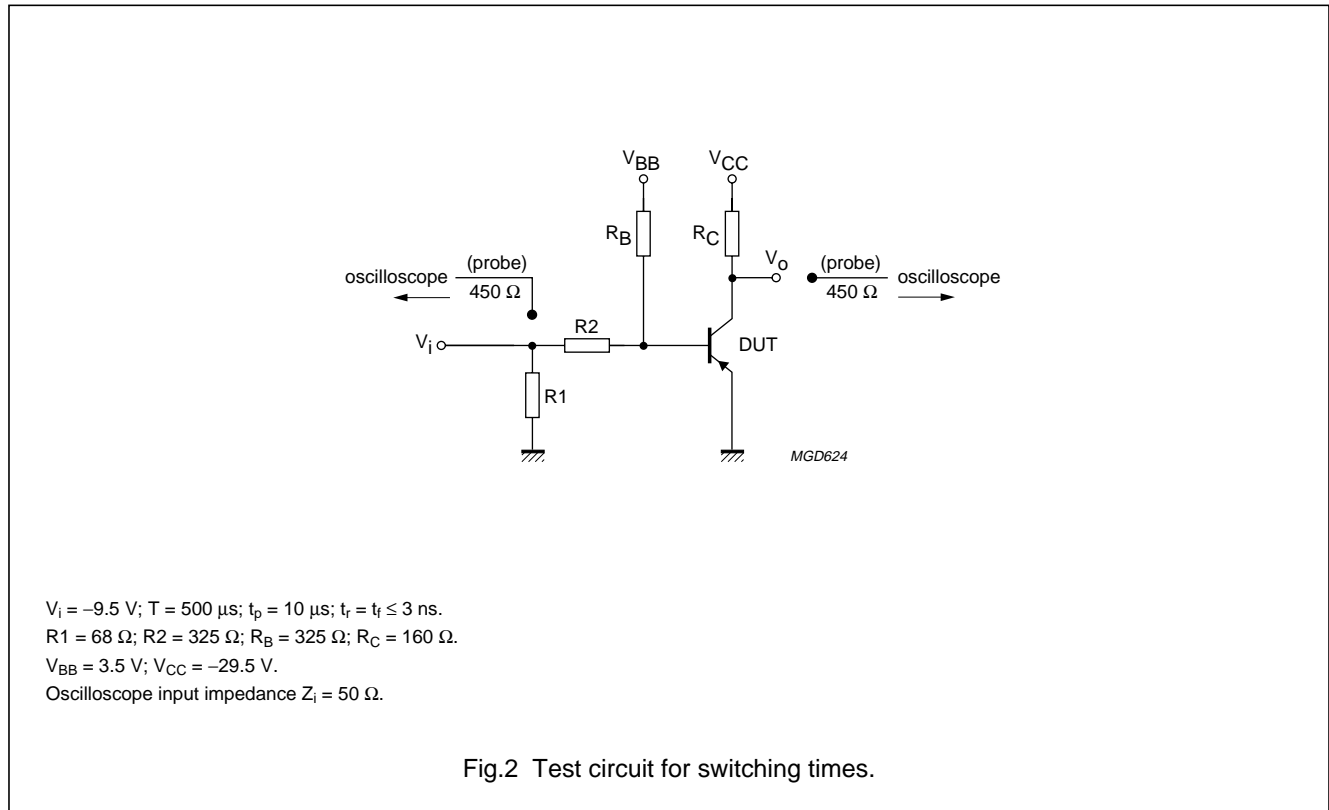
PNP switching transistor

PMST2907A

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
f_T	transition frequency	$I_C = -50 \text{ mA}$; $V_{CE} = -20 \text{ V}$; $f = 100 \text{ MHz}$; note 1	200	–	MHz
Switching times (between 10% and 90% levels); see Fig.2					
t_{on}	turn-on time	$I_{Con} = -150 \text{ mA}$; $I_{Bon} = -15 \text{ mA}$; $I_{Boff} = 15 \text{ mA}$	–	45	ns
t_d	delay time		–	15	ns
t_r	rise time		–	35	ns
t_{off}	turn-off time		–	300	ns
t_s	storage time		–	250	ns
t_f	fall time		–	50	ns

Note

1. Pulse test: $t_p \leq 300 \mu\text{s}$; $\delta \leq 0.02$.



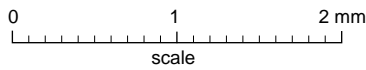
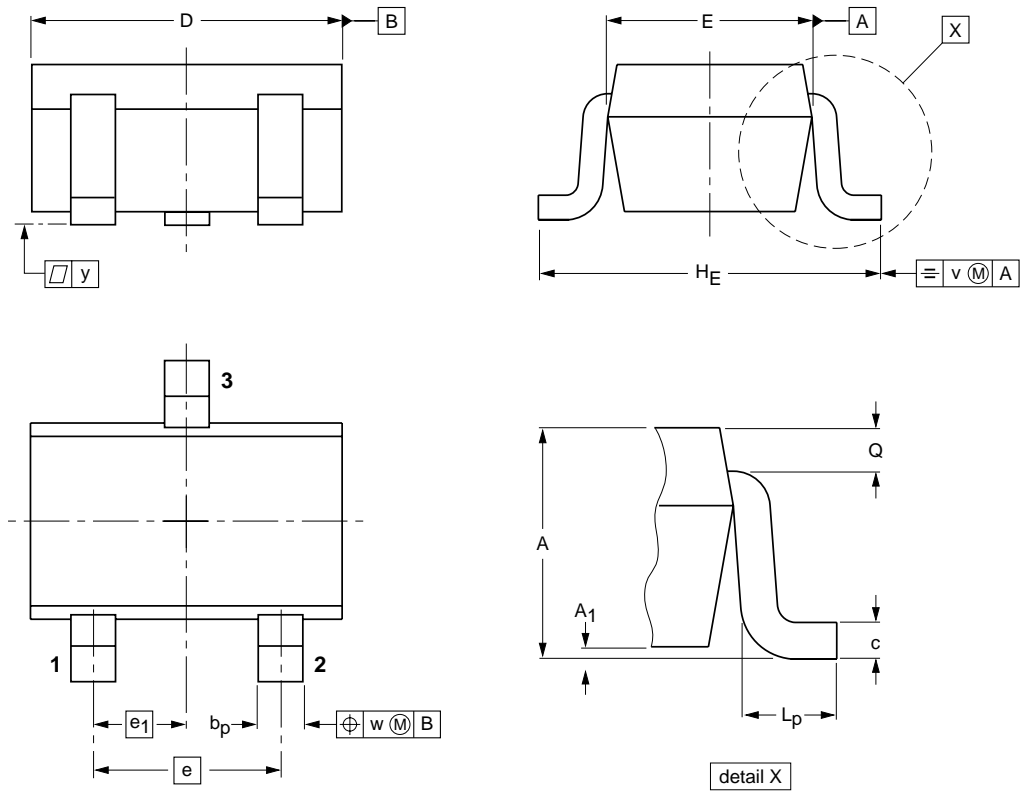
PNP switching transistor

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PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT323



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	1.1 0.8	0.1	0.4 0.3	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT323			SC-70			97-02-28

PNP switching transistor

PMST2907A

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

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PNP switching transistor

PMST2907A

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